NSN 5961-01-116-1285

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View Online at https://aerobasegroup.com/nsn/5961-01-116-1285 **Inclosure Material:** Metal **Overall Length:** Between 1.553 inches and 1.573 inches **Overall Height:** 0.762 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Burn in and hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -80.0 collector to base voltage, dc and -80.0 collector to emitter voltage, dc and -5.0 emitter to base voltage, instantaneous **Current Rating Per Characteristic:** -25.00 amperes source cutoff current **Power Rating Per Characteristic:** 200.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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No